#### **Pressure**

MPX2010

## **Freescale Semiconductor**

### 10 kPa On-Chip Temperature **Compensated and Calibrated** Silicon Pressure Sensors

The MPX2010 series silicon piezoresistive pressure sensors provide a very accurate and linear voltage output directly proportional to the applied pressure. These sensors house a single monolithic silicon die with the strain gauge and thin film resistor network integrated. The sensor is laser trimmed for precise span, offset calibration and temperature compensation.

#### **Features**

- Temperature Compensated over 0°C to +85°C
- · Ratiometric to Supply Voltage
- Differential and Gauge Options
- · Available in Easy-to-Use Tape & Reel

# Rev 13, 10/2008

### **MPX2010** Series

0 to 10 kPa (0 to 1.45 psi) 25 mV Full Scale (Typical)

#### Application Examples

- Respiratory Diagnostics
- Air Movement Control
- Controllers
- Pressure Switching

| ORDERING INFORMATION |                 |           |            |             |   |               |              |          |                |
|----------------------|-----------------|-----------|------------|-------------|---|---------------|--------------|----------|----------------|
| Device Name          | Package         | Case      | # of Ports |             |   | Pressure Type |              |          | Davias Marking |
| Device Name          | Options         | No.       | None       | Single Dual |   | Gauge         | Differential | Absolute | Device Marking |
| Small Outline Pac    | kage (MPXV2010  | ) Series) |            |             |   |               | •            |          | ·              |
| MPXV2010GP           | Tray            | 1369      |            | •           |   | •             |              |          | MPXV2010GP     |
| MPXV2010DP           | Tray            | 1351      |            |             | • |               | •            |          | MPXV2010DP     |
| Unibody Package      | (MPX2010 Serie  | s)        |            |             |   |               |              | •        | •              |
| MPX2010D             | Tray            | 344       | •          |             |   |               | •            |          | MPX2010D       |
| MPX2010DP            | Tray            | 344C      |            |             | • |               | •            |          | MPX2010DP      |
| MPX2010GP            | Tray            | 344B      |            | •           |   | •             |              |          | MPX2010GP      |
| MPX2010GS            | Tray            | 344E      |            | •           |   | •             |              |          | MPX2010D       |
| MPX2010GSX           | Tray            | 344F      |            | •           |   | •             |              |          | MPX2010D       |
| MPAK Package (N      | IPXM2010 Series | 5)        |            |             |   | •             |              |          |                |
| MPXM2010D            | Rail            | 1320      | •          |             |   |               | •            |          | MPXM2010D      |
| MPXM2010DT1          | Tape and Reel   | 1320      | •          |             |   |               | •            |          | MPXM2010D      |
| MPXM2010GS           | Rail            | 1320A     |            | •           |   | •             |              |          | MPXM2010GS     |
| MPXM2010GST1         | Tape and Reel   | 1320A     |            | •           |   | •             |              |          | MPXM2010GS     |

#### SMALL OUTLINE PACKAGES

MPXV2010GP CASE 1369-01



**MPX2010GP** 

CASE 344B-01

MPXM2010D/DT1 CASE 1320-02

MPXM2010GS/GST1 CASE 1320A-02

#### **UNIBODY PACKAGES**



MPX2010DP CASE 344C-01



MPX2010GSX CASE 344F-01



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MPX2010D

CASE 344-15



**MPAK PACKAGES** 

**MPX2010GS** 

CASE 344E-01



### **Operating Characteristics**

| <b>Table 1. Operating Characteristics</b> ( $V_S = 10 V_{DC}$ , $T_A = 25^{\circ}C$ unless otherwise noted, P1 > P2) |
|--|
|--|

| Characteristic                             | Symbol             | Min  | Тур  | Max  | Units             |
|--|--------------------|------|------|------|-------------------|
| Pressure Range <sup>(1)</sup>              | P <sub>OP</sub>    | 0    | _    | 10   | kPa               |
| Supply Voltage <sup>(2)</sup>              | Vs                 |      | 10   | 16   | V <sub>DC</sub>   |
| Supply Current                             | lo                 |      | 6.0  | _    | mAdc              |
| Full Scale Span <sup>(3)</sup>             | V <sub>FSS</sub>   | 24   | 25   | 26   | mV                |
| Offset <sup>(4)</sup>                      | V <sub>OFF</sub>   | -1.0 | _    | 1.0  | mV                |
| Sensitivity                                | ΔV/ΔΡ              |      | 2.5  | _    | mV/kPa            |
| Linearity                                  | _                  | -1.0 | _    | 1.0  | %V <sub>FSS</sub> |
| Pressure Hysteresis (0 to 10 kPa)          | _                  |      | ±0.1 | _    | %V <sub>FSS</sub> |
| Temperature Hysteresis (-40°C to +125°C)   | _                  |      | ±0.5 | _    | %V <sub>FSS</sub> |
| Temperature Coefficient on Full Scale Span | TCV <sub>FSS</sub> | -1.0 | _    | 1.0  | %V <sub>FSS</sub> |
| Temperature Coefficient on Offset          | TCV <sub>OFF</sub> | -1.0 | _    | 1.0  | mV                |
| Input Impedance                            | Z <sub>IN</sub>    | 1300 | _    | 2550 | Ω                 |
| Output Impedance                           | Z <sub>OUT</sub>   | 1400 | _    | 3000 | Ω                 |
| Response Time <sup>(5)</sup> (10% to 90%)  | t <sub>R</sub>     | _    | 1.0  | _    | ms                |
| Warm-Up Time                               | _                  | _    | 20   | _    | ms                |
| Offset Stability <sup>(6)</sup>            | _                  | _    | ±0.5 | _    | %V <sub>FSS</sub> |

1. 1.0 kPa (kiloPascal) equals 0.145 psi.

2. Device is ratiometric within this specified excitation range. Operating the device at a different range may induce additional error due to device self-heating.

3. Full Scale Span (V<sub>FSS</sub>) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.

4. Offset (V<sub>OFF</sub>) is defined as the output voltage at the minimum rated pressure.

5. Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.

6. Offset stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

#### **Maximum Ratings**

#### Table 2. Maximum Ratings<sup>(1)</sup>

| Rating                     | Symbol             | Value       | Unit |
|----------------------------|--------------------|-------------|------|
| Maximum Pressure (P1 > P2) | P <sub>MAX</sub>   | 75          | kPa  |
| Burst Pressure (P1 > P2)   | P <sub>BURST</sub> | 100         | kPa  |
| Storage Temperature        | T <sub>STG</sub>   | -40 to +125 | ٦°   |
| Operating Temperature      | T <sub>A</sub>     | -40 to +125 | °C   |

1. Exposure beyond the specified limits may cause permanent damage or degradation to the device.

#### **Voltage Output versus Applied Differential Pressure**

The output voltage of the differential or gauge sensor increases with increasing pressure applied to the pressure side (P1) relative to the vacuum side (P2). Similarly, output voltage increases as increasing vacuum is applied to the vacuum side (P2) relative to the pressure side (P1). Figure 1. shows a block diagram of the internal circuitry on the stand-alone pressure sensor chip.

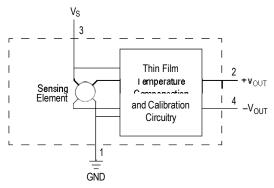


Figure 1. Temperature Compensated and Calibrated Pressure Sensor Schematic

#### **On-Chip Temperature Compensation and Calibration**

Figure 2. shows the output characteristics of the MPX2010 series at 25°C. The output is directly proportional to the differential pressure and is essentially a straight line.

The effects of temperature on full scale span and offset are very small and are shown under Operating Characteristics.

This performance over temperature is achieved by having both the shear stress strain gauge and the thin-film resistor circuitry on the same silicon diaphragm. Each chip is dynamically laser trimmed for precise span and offset calibration and temperature compensation.

Figure 3. illustrates the differential/gauge die in the basic chip carrier (Case 344). A silicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the silicon diaphragm.

The MPX2010 series pressure sensor operating characteristics and internal reliability and qualification tests are based on use of dry air as the pressure media. Media other than dry air may have adverse effects on sensor performance and long term reliability. Contact the factory for information regarding media compatibility in your application.

#### LINEARITY

Linearity refers to how well a transducer's output follows the equation:  $V_{out} = V_{off}$  + sensitivity x P over the operating pressure range. There are two basic methods for calculating nonlinearity: (1) end point straight line fit (see Figure 4.) or (2) a least squares best line fit. While a least squares fit gives the "best case" linearity error (lower numerical value), the calculations required are burdensome.

Conversely, an end point fit will give the "worst case" error (often more desirable in error budget calculations) and the calculations are more straightforward for the user. Freescale's specified pressure sensor linearities are based on the end point straight line method measured at the midrange pressure.

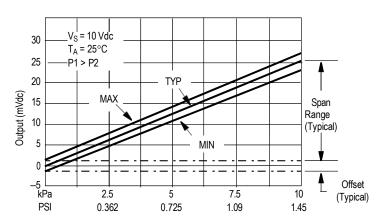


Figure 2. Output vs. Pressure Differential

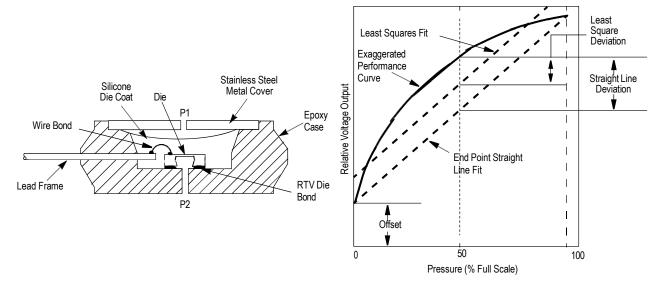


Figure 3. Unibody Package: Cross Sectional Diagram (not to scale)

Figure 4. Linearity Specification Comparison

#### MPX2010

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